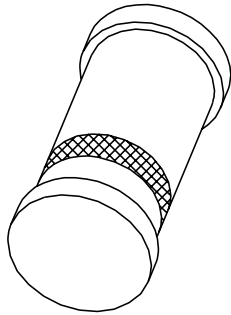


# DATA SHEET



Datasheet.Live

**PMLL4150; PMLL4151;  
PMLL4153**  
High-speed diodes

Product specification  
Supersedes data of April 1996

1996 Sep 18

## High-speed diodes

## PMLL4150; PMLL4151; PMLL4153

### FEATURES

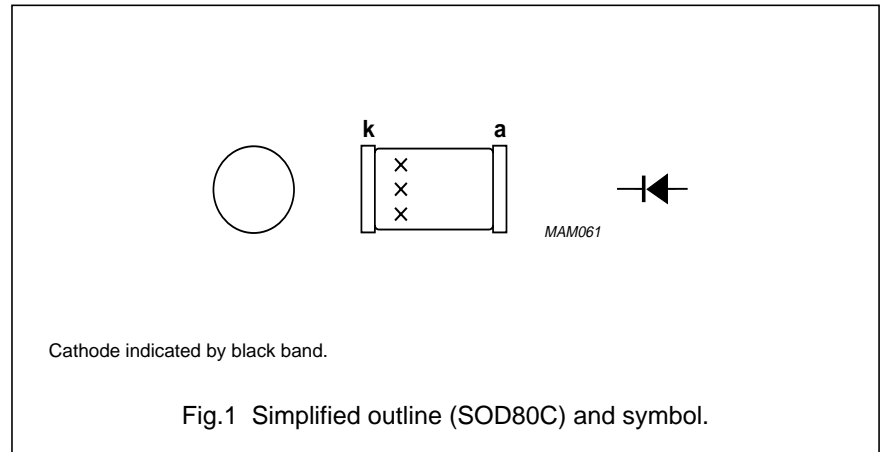
- Small hermetically sealed glass SMD package
- High switching speed: max. 4 ns
- General application
- Continuous reverse voltage: max. 50 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 600 mA and 450 mA respectively.

### APPLICATIONS

- High-speed switching
- The PMLL4150 is primarily intended for general purpose use in computer and industrial applications.
- The PMLL4151 and PMLL4153 are intended for military and industrial applications.

### DESCRIPTION

The PMLL4150, PMLL4151, PMLL4153 are high-speed switching diodes fabricated in planar technology, and encapsulated in small hermetically sealed glass SOD80C SMD packages.



## High-speed diodes

## PMLL4150; PMLL4151; PMLL4153

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage				
	PMLL4151		–	75	V
	PMLL4153		–	75	V
$V_R$	continuous reverse voltage		–	50	V
$I_F$	continuous forward current	see Fig.2; note 1			
	PMLL4150		–	300	mA
	PMLL4151		–	200	mA
	PMLL4153		–	200	mA
$I_{FRM}$	repetitive peak forward current				
	PMLL4150		–	600	mA
	PMLL4151		–	450	mA
	PMLL4153		–	450	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4			
		$t = 1\ \mu\text{s}$	–	4	A
		$t = 1\ \text{ms}$	–	1	A
		$t = 1\ \text{s}$	–	0.5	A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	200	°C

**Note**

1. Device mounted on an FR4 printed-circuit board.

## High-speed diodes

## PMLL4150; PMLL4151; PMLL4153

**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ }^\circ\text{C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage PMLL4150  PMLL4151 PMLL4153	see Fig.3			
		$I_F = 1\text{ mA}$	540	620	mV
		$I_F = 10\text{ mA}$	660	740	mV
		$I_F = 50\text{ mA}$	760	860	mV
		$I_F = 100\text{ mA}$	820	920	mV
		$I_F = 200\text{ mA}$	870	1000	mV
		$I_F = 50\text{ mA}$	–	1000	mV
		$I_F = 0.1\text{ mA}$	490	550	mV
		$I_F = 0.25\text{ mA}$	530	590	mV
		$I_F = 1\text{ mA}$	590	670	mV
		$I_F = 2\text{ mA}$	620	700	mV
		$I_F = 10\text{ mA}$	700	810	mV
$I_F = 50\text{ mA}$	740	880	mV		
$I_R$	reverse current PMLL4150 PMLL4151 PMLL4153	$V_R = 50\text{ V}$ ; see Fig.5	–	0.1	$\mu\text{A}$
			–	0.05	$\mu\text{A}$
			–	0.05	$\mu\text{A}$
$I_R$	reverse current PMLL4150 PMLL4151 PMLL4153	$V_R = 50\text{ V}$ ; $T_j = 150\text{ }^\circ\text{C}$ ; see Fig.5	–	100	$\mu\text{A}$
			–	50	$\mu\text{A}$
			–	50	$\mu\text{A}$
$C_d$	diode capacitance PMLL4150 PMLL4151 PMLL4153	$f = 1\text{ MHz}$ ; $V_R = 0$ ; see Fig.6	–	2.5	pF
			–	2	pF
			–	2	pF

## High-speed diodes

## PMLL4150; PMLL4151; PMLL4153

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$t_{rr}$	reverse recovery time PMLL4150	when switched from $I_F = 10$ mA to $I_R = 1$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 0.1$ mA; see Fig.7	–	6	ns
		when switched from $I_F = 10$ mA to 200 mA to $I_R = 10$ mA to 200 mA; $R_L = 100 \Omega$ ; measured at $I_R = 0.1 \times I_F$ ; see Fig.7	–	4	ns
		when switched from $I_F = 200$ mA to 400 mA to $I_R = 200$ mA to 400 mA; $R_L = 100 \Omega$ ; measured at $I_R = 0.1 \times I_F$ ; see Fig.7	–	6	ns
$t_{rr}$	reverse recovery time PMLL4151	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	–	4	ns
		when switched from $I_F = 10$ mA to $I_R = 60$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	–	2	ns
$t_{rr}$	reverse recovery time PMLL4153	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	–	4	ns
		when switched from $I_F = 10$ mA to $I_R = 60$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	–	2	ns
$t_{fr}$	forward recovery time	when switched to $I_F = 200$ mA; $t_r = 0.4$ ns; measured at $V_F = 1$ V; see Fig.8	–	10	ns

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th j-tp}$	thermal resistance from junction to tie-point		300	K/W
$R_{th j-a}$	thermal resistance from junction to ambient	note 1	350	K/W

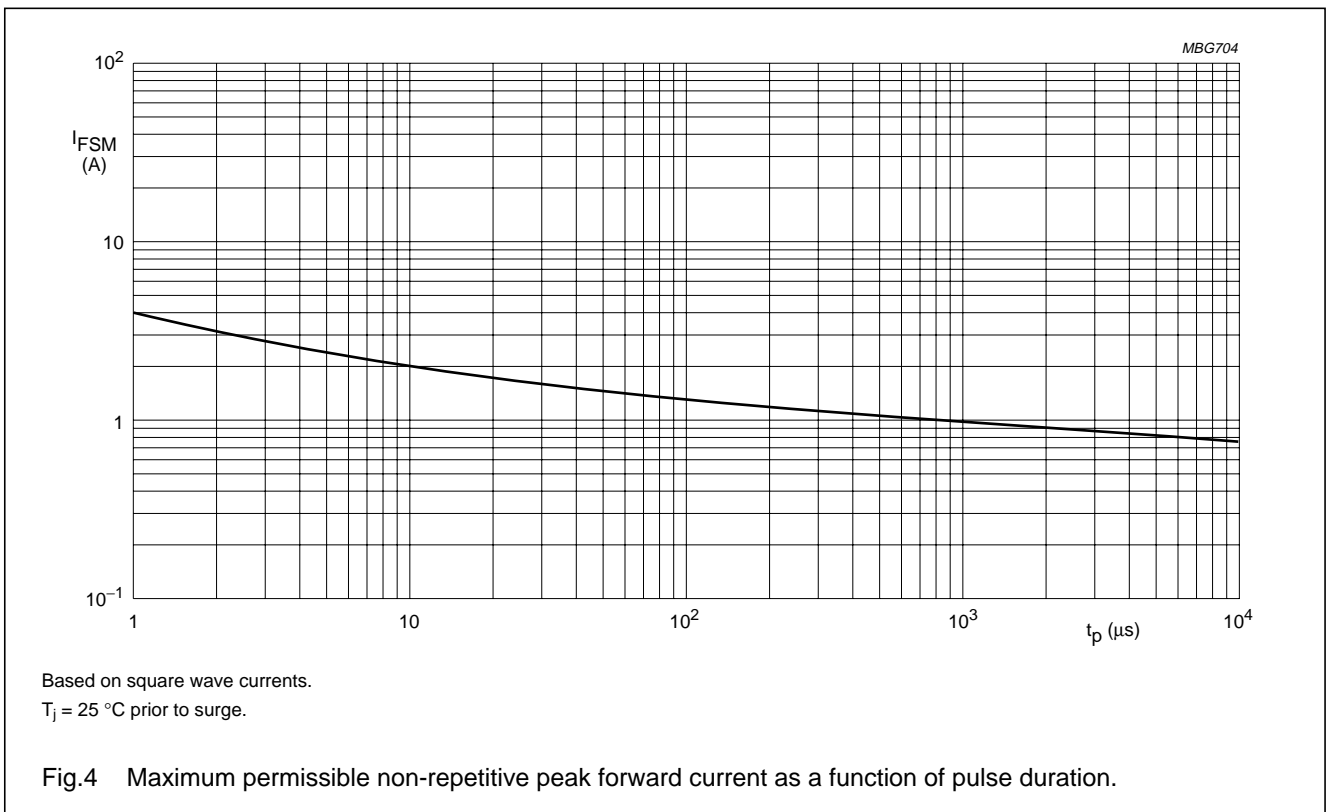
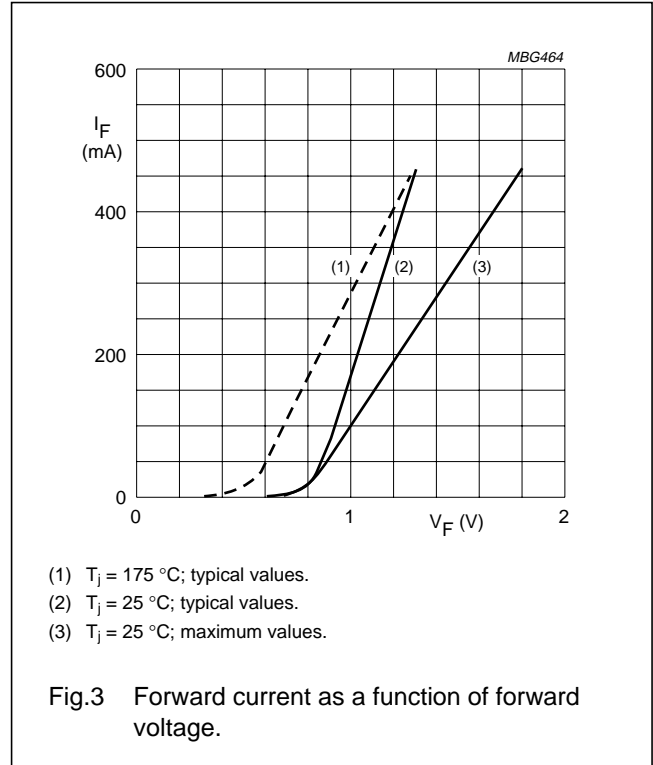
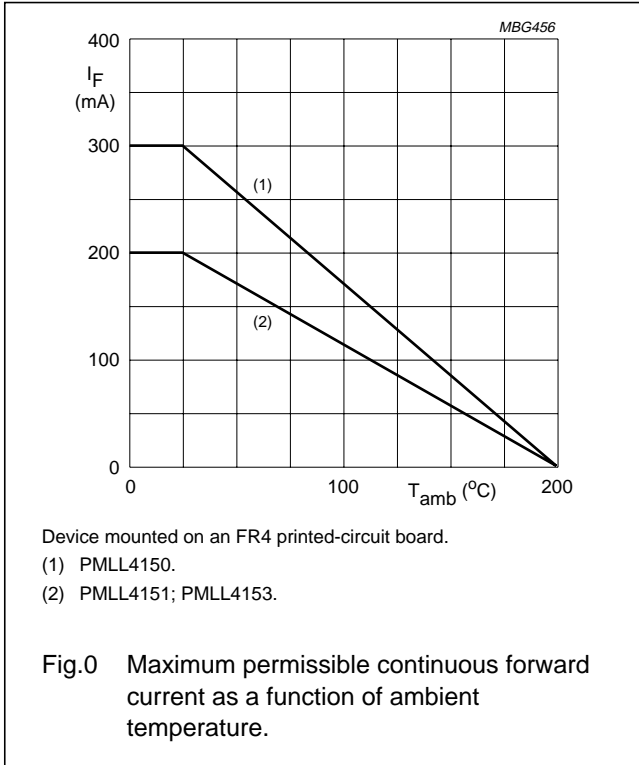
## Note

1. Device mounted on an FR4 printed-circuit board.

High-speed diodes

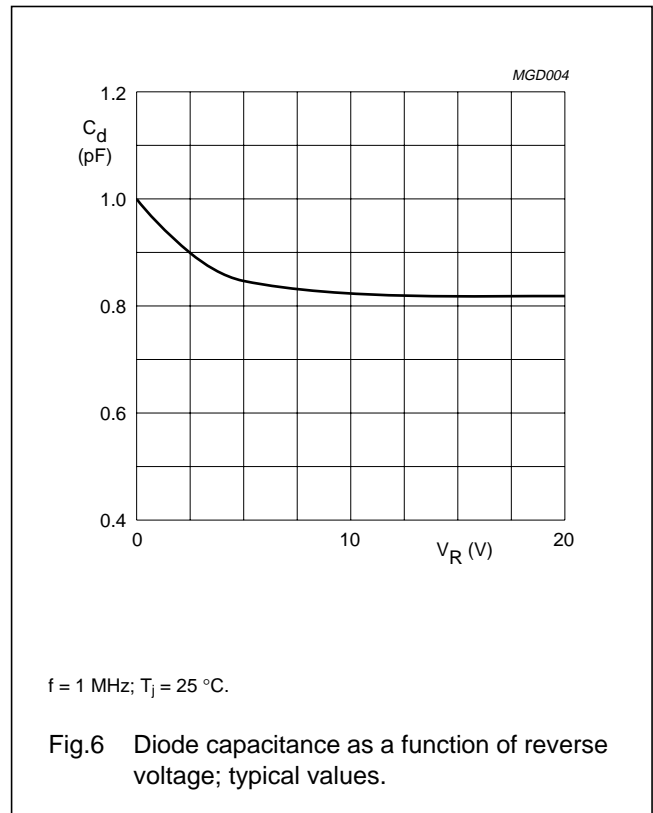
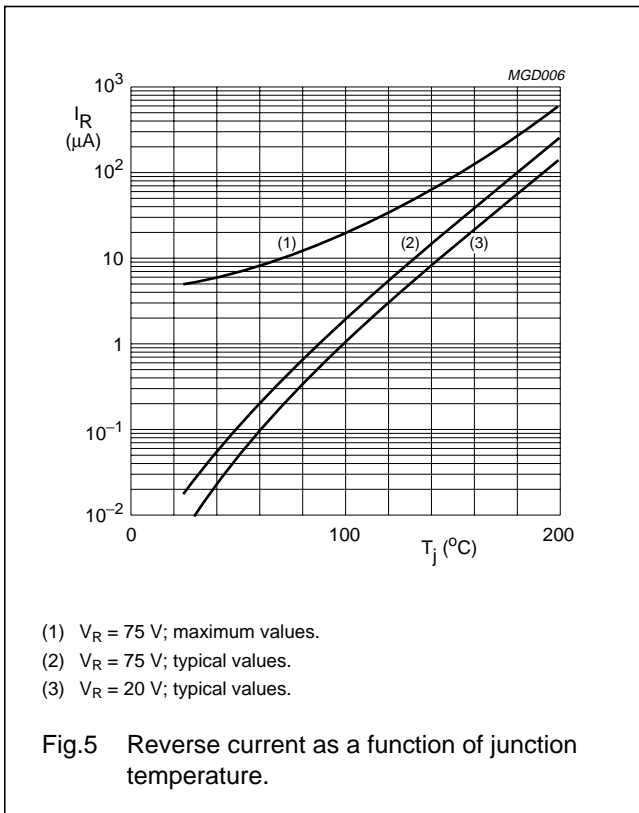
PMLL4150; PMLL4151; PMLL4153

GRAPHICAL DATA



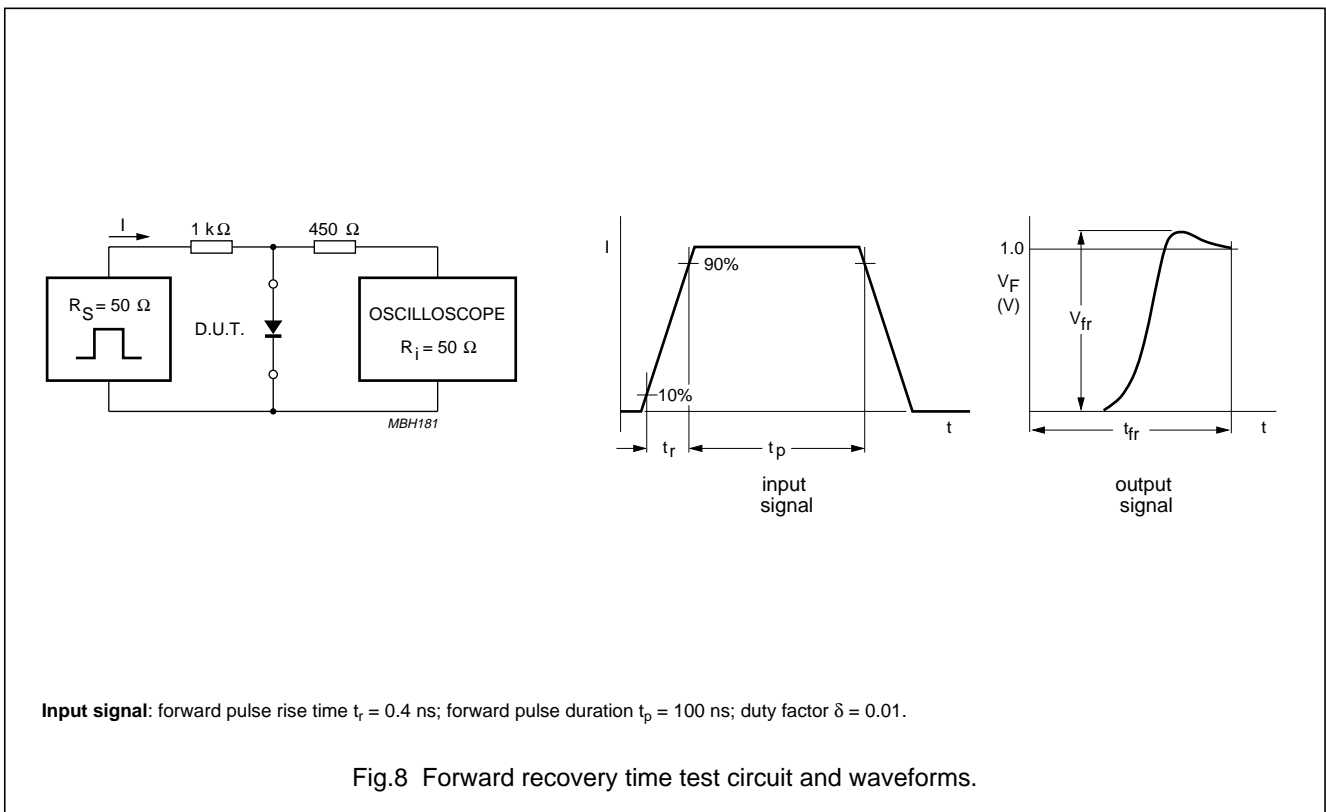
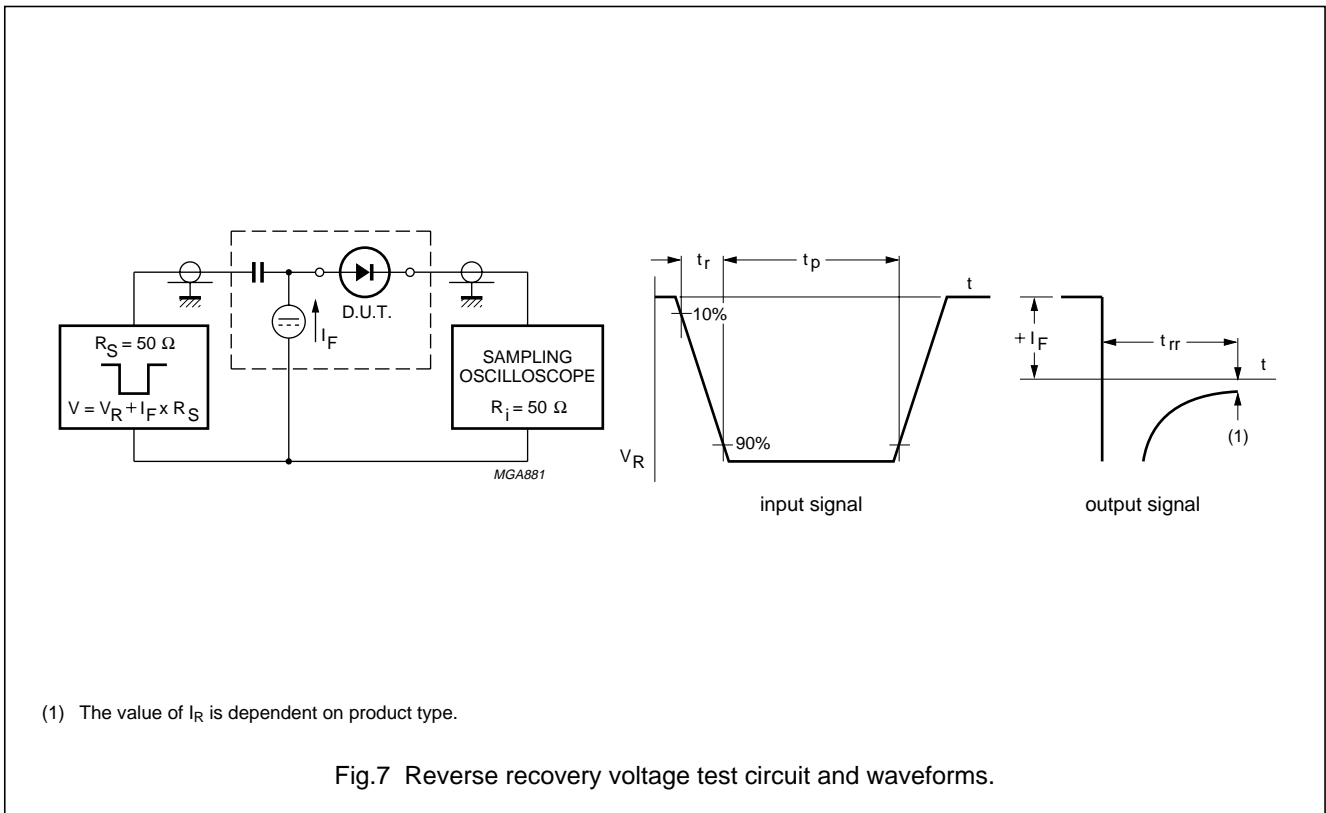
High-speed diodes

PMLL4150; PMLL4151; PMLL4153



High-speed diodes

PMLL4150; PMLL4151; PMLL4153

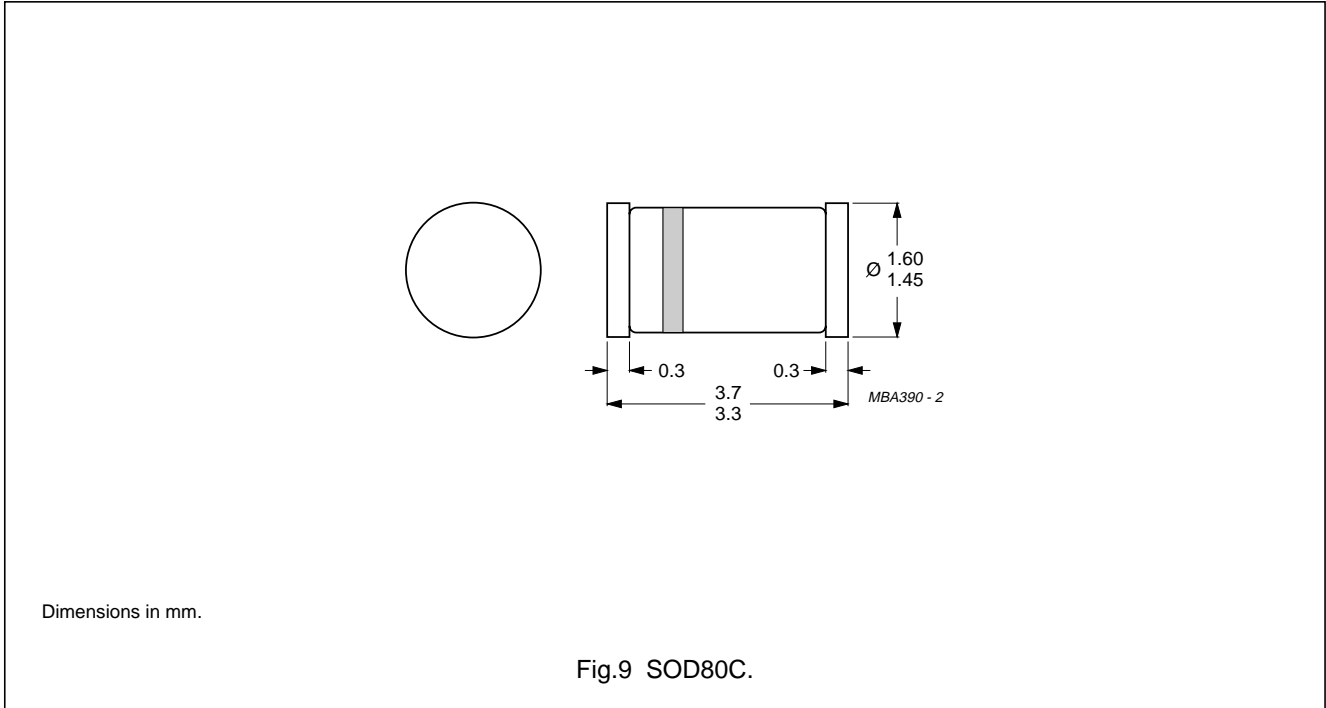




High-speed diodes

PMLL4150; PMLL4151; PMLL4153

PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.